# NSN 5961-01-091-1749

Transistor - Page 1 of 1



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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.250 inches and 0.450 inches

# **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

## To-3

Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

# **Criticality Code Justification:**

Feat

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 70.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage,

static, collector open

## **Current Rating Per Characteristic:**

Between 7.00 amperes source cutoff current and 15.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

6.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Item must comply with requirements of defense electronics supply center production standard no. L02861; for navy nuclear propulsion plant products only; junction pattern arrangement: npn

## **Terminal Type And Quantity:**

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

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# Demilitarization:

No

Fiig:

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